

IN THE CLAIMS:

Please amend the claims as indicated below.

Please cancel unelected claims 1-15 and 22-26, without prejudice.

1-15 (Cancelled).

16. (Previously Presented) A method for reducing leakage current in a read only memory device, comprising the step of:

precharging at least one memory column in said read only memory device during a precharge phase of each read cycle, wherein at least one memory column is not precharged during a standby phase.

17. (Original) The method of claim 16, further comprising the step of terminating said precharge phase by a clock edge.

18. (Original) The method of claim 16, wherein said precharge phase is internally timed out prior to a subsequent clock edge.

19. (Previously Presented) A read only memory device comprised of memory columns that are connected to a precharge power supply during a precharge portion of each read cycle and are not connected to a precharge power supply during a standby mode.

20. (Original) The read only memory device of claim 19, wherein said read only memory device is further configured to terminate said precharge phase by a clock edge.

21. (Original) The read only memory device of claim 19, wherein said precharge phase is internally timed out prior to a subsequent clock edge.

22-26 (Cancelled).